

# 5 V SPST Depletion Switch with Negative Swing

# **FSA515**

# **Description**

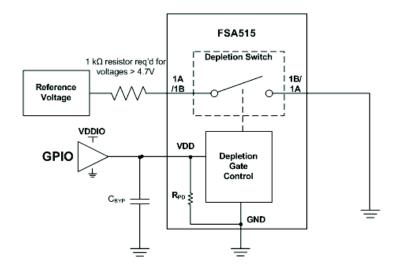
The FSA515 is a high-performance single-pole single-throw (SPST) depletion switch. The depletion technology allows the device to conduct signals when there is no  $V_{DD}$  is available and to isolate signals when  $V_{DD}$  is present. The FSA515 is 5.5 V tolerant and can pass or isolate negative signal swings down to -3.0 V.

# **Features**

- SPST Depletion Switch
- Normally Closed when  $V_{DD} < 0.5 \text{ V}$
- $V_{SW}$ : -3.0 V to +5.5 V
- R<sub>ON</sub>: 0.7 Ω (Typical)
- R<sub>FLAT</sub>: 1.1 mΩ (Typical)

# **Typical Applications**

- Mobile Accessories, Adapters, and Cables
- Phones, Tablets, and Laptops
- Headsets



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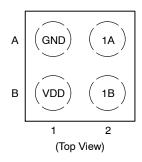
WLCSP4 CASE 567VT

### **MARKING DIAGRAM**



VM = Specific Device Code
XX = 2-digit Lot Run Code
YY = 2-digit Date Code
Z = 1-digit Plant Code

### PIN CONNECTIONS



### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
FSA515UCX	WLCSP4 (Pb-Free)	3000 / Tape & Reel

† For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

# **Table 1. PIN FUNCTION DESCRIPTION**

Pin No. (WLCSP4)	Pin Name	Description
A1 GND Ground		Ground
A2 1A A-Port of Switch 1 (Normally Closed)		A-Port of Switch 1 (Normally Closed)
B1	1 VDD Supply Voltage (Switch is closed when Low)	
B2	1B	B-Port of Switch 1 (Normally Closed)

# **Table 2. SWITCH TRUTH TABLE**

VDD	Switch State
Low	ON (Conducting)
High	OFF (Isolating)

# **Table 3. RECOMMENDED EXTERNAL COMPONENT**

Component	Description	Vendor	Parameter	Min	Тур	Unit
C <sub>BYP</sub>	0402, 1 nF, 10%, 6.3 V, X7R	Kemet C0402C102K9RACTU	С	0.65	1	nF
	0201, 1 nF, 10%, 6.3 V, X7R	AVX 02016C102KAT2A				

### **Table 4. MAXIMUM RATINGS**

	Rating		Symbol	Value	Unit
Supply Voltage			$V_{DD}$	-0.5 to 6.0	V
Switch Voltage Range DC Switch I/O Voltage (Switch Conducting)		V <sub>SW(ON)</sub>	-3.6 (AC) to 6.0	V	
	DC Switch I/O Voltage (Sw	DC Switch I/O Voltage (Switch Isolated)		-3.6 (AC) to 6.0	V
Maximum DC Switch I/O Curre	I <sub>SW</sub>	350	mA		
Maximum Peak Switch I/O Current -Pulsed at 1ms duration, <10% duty cycle			I <sub>SWPEAK</sub>	500	mA
Maximum Junction Temperatur	re		T <sub>J(max)</sub>	150	°C
Storage Temperature Range			TSTG	-65 to 150	°C
ESD Capability (Note 2)	pability (Note 2) Human Body Model		ESDHBM	4	kV
Charged Device Model			ESDCDM	2	kV
	IEC 61000-4-2 System	Contact	ESDIEC	8	kV
		Air Gap		15	kV

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Refer to ELECTRICAL CHARACTERISTICS, RECOMMENDED OPERATING RANGES and/or APPLICATION INFORMATION for Safe

ESD Human Body Model tested per ANSI,ESDA,JEDEC JS-001-2012

ESD Charged Device Model tested per According to "EIA/JESD22-C101 Level III"

Latchup Current Maximum Rating: 100 mA per JEDEC standard: JESD78

### **Table 5. THERMAL CHARACTERISTICS**

Rating	Symbol	Value	Unit
Thermal Characteristics, WLCSP4 Thermal Resistance, Junction-to-Air (Note 3)	$R_{ hetaJA}$	77.4	°C/W

3. JEDEC Standard, Still Air, 4-layer board with vias

Operating parameters.

<sup>2.</sup> This device series incorporates ESD protection and is tested by the following methods:

**Table 6. RECOMMENDED OPERATING RANGES** 

	Rating	Symbol	Min	Max	Unit
Supply Voltage	Isolating	V <sub>DD (OFF)</sub>	2.5	5.5	V
	Conducting	V <sub>DD (ON)</sub>	0	0.5	V
Switch Voltage Range	Isolating	V <sub>SW(OFF)</sub>	-3.0 (Vpk; AC)	4.7	V
	Isolating (requires 1 $k\Omega$ (typ) in series with source)		4.7	5.5	
	Conducting	V <sub>SW(ON)</sub>	-3.0 (Vpk; AC)	4.7	V
	Isolating (requires 1 $k\Omega$ (typ) in series with source)	1	4.7	5.5	
Ambient Temperature		T <sub>A</sub>	-40	85	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

Table 7. ELECTRICAL CHARACTERISTICSUnless otherwise specified, typical values are for  $T_A = 25$  °C,  $V_{DD} = 0$  V

Parameter	Test Co	nditions	Symbol	Min	Тур	Max	Unit
SWITCH DC CHARACTERISTICS	3					-	•
Switch Off Leakage Current	$V_{DD} = 5 V$	1A = 5.5 V	I <sub>OFF</sub>		0.01		μΑ
	1B = GND	1A = -1.5 V	1		-0.65		1
	V <sub>DD</sub> = 3.3 V 1B = GND	1A = 1.4 V (Note 5)			0.01	1.5	
Switch On Resistance	I <sub>SW</sub> = 100 mA, V <sub>SV</sub>	<sub>V</sub> =-1.5 V to +1.5 V	R <sub>ON</sub>		0.7	1.1	Ω
	I <sub>SW</sub> = 100 mA, V <sub>S</sub>	<sub>W</sub> = 0 V to +5.5 V	1		0.7	1.1	1
On Resistance Flatness	I <sub>SW</sub> = 100 mA, V <sub>SV</sub>	<sub>V</sub> =-1.5 V to +1.5 V	R <sub>FLAT(ON)</sub>		1.1		mΩ
	I <sub>SW</sub> = 100 mA, V <sub>S</sub>	<sub>W</sub> = 0 V to +5.5 V	1		1.1		1
SWITCH AC CHARACTERISTICS	3						
Total Harmonic Distortion Plus Noise	$V_{SW} = 1 V_{RMS}$ , $Q_{L} = 32 \Omega$		THD+N		-93		dB
Off Isolation Rejection Ratio	V <sub>SW</sub> = 1 V <sub>RMS</sub> ,	f = 1 kHz	OIRR		-116		dB
	Ground Centered $R_L = 32 \Omega$	f = 20 kHz			-97		1
Bandwidth		$V_{SW}$ = 200 m $V_{PP}$ , Ground Centered $R_L$ = 50 $\Omega$			367		MHz
SUPPLY CURRENTS	•		•		•		•
Peak Startup Supply Current	V <sub>DD</sub> = 0 \	/ to 5.5 V	I <sub>DDT</sub>		3.0		mA
Quiescent Current	V <sub>DD</sub> =	5.5 V	I <sub>DD</sub>	-	30		μΑ
Disable Current	V <sub>DD</sub> ≤	0.2 V	I <sub>DIS</sub>		0.05	0.50	μΑ
CONTROL LOGIC	•					-	•
V <sub>DD</sub> Pull-Down Resistance	V <sub>DD</sub> ≤	0.2 V	$R_{PD}$		5.8		МΩ
V <sub>DD</sub> High Voltage			$V_{DDH}$	2.5			V
V <sub>DD</sub> Low Voltage			$V_{DDL}$			0.5	V
TIMING							
Switch Turn-off Time	$R_L$ =1 kΩ, $C_L$ =10 pF, $V_{DD}$ = 0.0 V to 3.0 V $V_{SW}$ = 5.0V, Figure 1		t <sub>OFF</sub>		85		μs
Switch Turn-on Time	$R_L$ =1 kΩ, $C_L$ =10 pF, $V_{DD}$ = 3.0 V to Hi-Z, $C_{BYP}$ = 1 nF, $V_{SW}$ = 5.0 V, Figure 1		t <sub>ON</sub>		250		μs

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. Performance guaranteed over the indicated operating temperature range by design and/or characterization tested at  $T_J = T_A = 25$  °C.

- 5. Maximum is guaranteed at 25 °C.
- 6. For reference only guaranteed by design.

Table 7. ELECTRICAL CHARACTERISTICS Unless otherwise specified, typical values are for TA = 25 °C, VDD = 0 V

Parameter	Test Conditions Symbol		Min	Тур	Max	Unit
CAPACITANCE	•					
On Capacitance	$R_L = 1 \text{ k}\Omega$	C <sub>ON</sub>		14		pF
Off Capacitance	$V_{DD}$ = 5 V, $R_L$ = 1 kΩ, $C_L$ = 10 pF	C <sub>OFF</sub>		17		pF
Supply Capacitance	V <sub>DD</sub> = 5 V with 400 mV <sub>PP</sub> , f = 1 MHz	C <sub>VDD</sub>		17		pF
OSCILLATOR FREQUENCY	•					
On-Chip Oscillator Frequency (Note 6)	For reference only	f <sub>OSC</sub>		110		kHz

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. Performance guaranteed over the indicated operating temperature range by design and/or characterization tested at T<sub>J</sub> = T<sub>A</sub> = 25 °C.

5. Maximum is guaranteed at 25 °C.

- 6. For reference only guaranteed by design.

# **TIMING DIAGRAM**

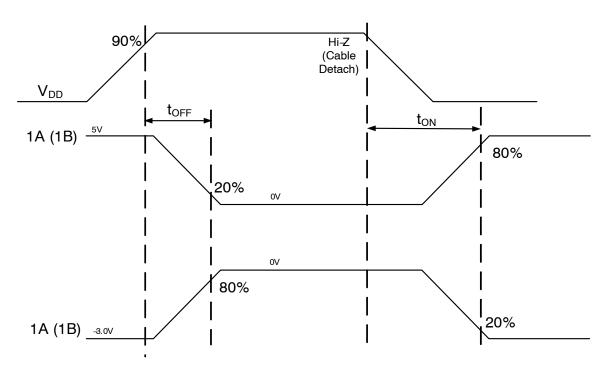


Figure 1.  $t_{\mbox{\scriptsize ON}}/\,t_{\mbox{\scriptsize OFF}}\,V_{\mbox{\scriptsize CC}}$  to Output Timing

# **REVISION HISTORY**

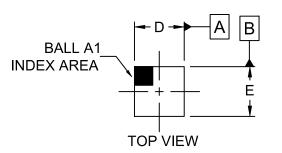
Revision	Description of Changes	Date
1	Rebranded the Data Sheet to <b>onsemi</b> format.	07/02/2025

This document has undergone updates prior to the inclusion of this revision history table. The changes tracked here only reflect updates made on the noted approval dates.



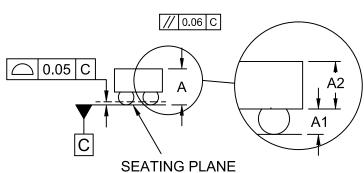
# **WLCSP4**, **0.815x0.815x0.457** CASE 567VT ISSUE O

**DATE 31 JAN 2018** 



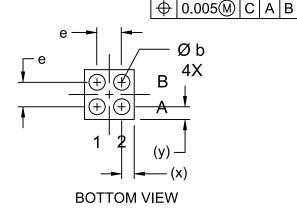
# NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. DATUM C APPLIES TO THE SPHERICAL CROWN OF THE SOLDER BALLS



SIDE VIEW DETAIL A

	MILLIMETERS				
DIM	MIN.	NOM.	MAX.		
Α	0.419	0.457	0.495		
A1	0.183	0.203	0.223		
A2	0.236	0.254	0.272		
b	0.240	0.260	0.280		
D	0.785	0.815	0.845		
E	0.785	0.815	0.845		
е	0.40 BSC				
Х	0.1925	0.2075	0.2225		
у	0.1925	0.2075	0.2225		



	0.215)Bottom Cu Pad
RECOMMENDED MOUNTING FOOTPRINT	

(NSMD PAD TYPE)

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DESCRIPTION:	WLCSP4, 0.815x0.815x0.457		PAGE 1 OF 1

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